

# PMPB11EN

## 30 V N-channel Trench MOSFET

Rev. 1 — 16 May 2012

Product data sheet

## 1. Product profile

### 1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 1.2 Features and benefits

- Trench MOSFET technology
- Very fast switching
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Tin-plated 100 % solderable side pads for optical solder inspection

### 1.3 Applications

- Charging switch for portable devices
- DC-to-DC converters
- Power management in battery-driven portables
- Hard disk and computing power management

### 1.4 Quick reference data

Table 1. Quick reference data

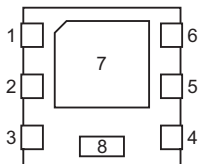
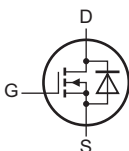
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$T_j = 25\text{ °C}$	-	-	30	V
$V_{GS}$	gate-source voltage		-20	-	20	V
$I_D$	drain current	$V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}; t \leq 5\text{ s}$	[1]	-	13	A
<b>Static characteristics</b>						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 9\text{ A}; T_j = 25\text{ °C}$	-	12	14.5	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



## 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	 <p>Transparent top view</p> <p><b>SOT1220 (DFN2020MD-6)</b></p>	 <p>017aaa253</p>
2	D	drain		
3	G	gate		
4	S	source		
5	D	drain		
6	D	drain		
7	D	drain		
8	S	source		

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMPB11EN	DFN2020MD-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220

## 4. Marking

Table 4. Marking codes

Type number	Marking code
PMPB11EN	1C

## 5. Limiting values

**Table 5. Limiting values**

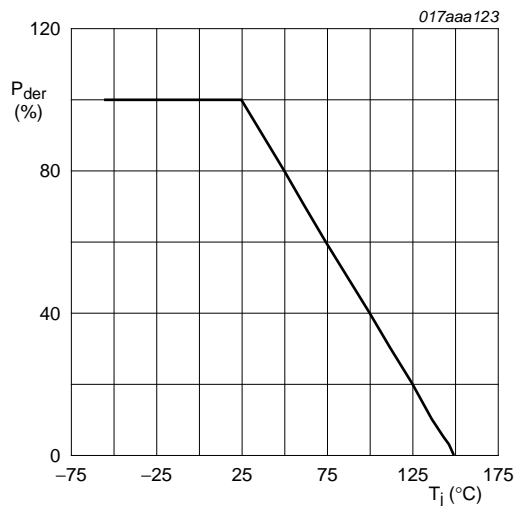
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$T_j = 25\text{ °C}$	-	30	V
$V_{GS}$	gate-source voltage		-20	20	V
$I_D$	drain current	$V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}; t \leq 5\text{ s}$	[1]	13	A
		$V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}$	[1]	9	A
		$V_{GS} = 10\text{ V}; T_{amb} = 100\text{ °C}$	[1]	5.7	A
$I_{DM}$	peak drain current	$T_{amb} = 25\text{ °C}; \text{single pulse}; t_p \leq 10\text{ }\mu\text{s}$	-	34	A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$	[1]	1.7	W
		$T_{amb} = 25\text{ °C}; t \leq 5\text{ s}$	[1]	3.5	W
		$T_{sp} = 25\text{ °C}$	-	12.5	W
$T_j$	junction temperature		-55	150	°C
$T_{amb}$	ambient temperature		-55	150	°C
$T_{stg}$	storage temperature		-65	150	°C

### Source-drain diode

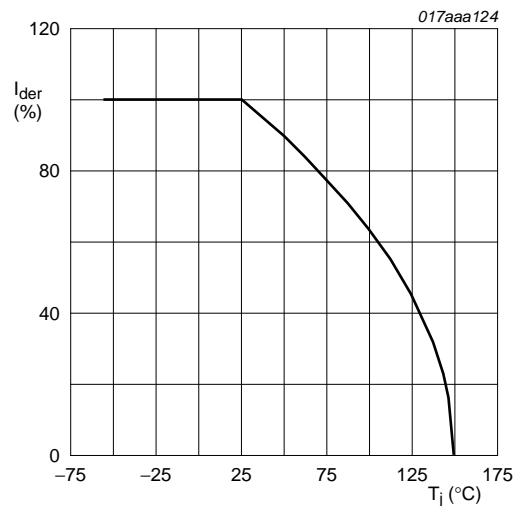
$I_S$	source current	$T_{amb} = 25\text{ °C}$	[1]	2.2	A
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[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



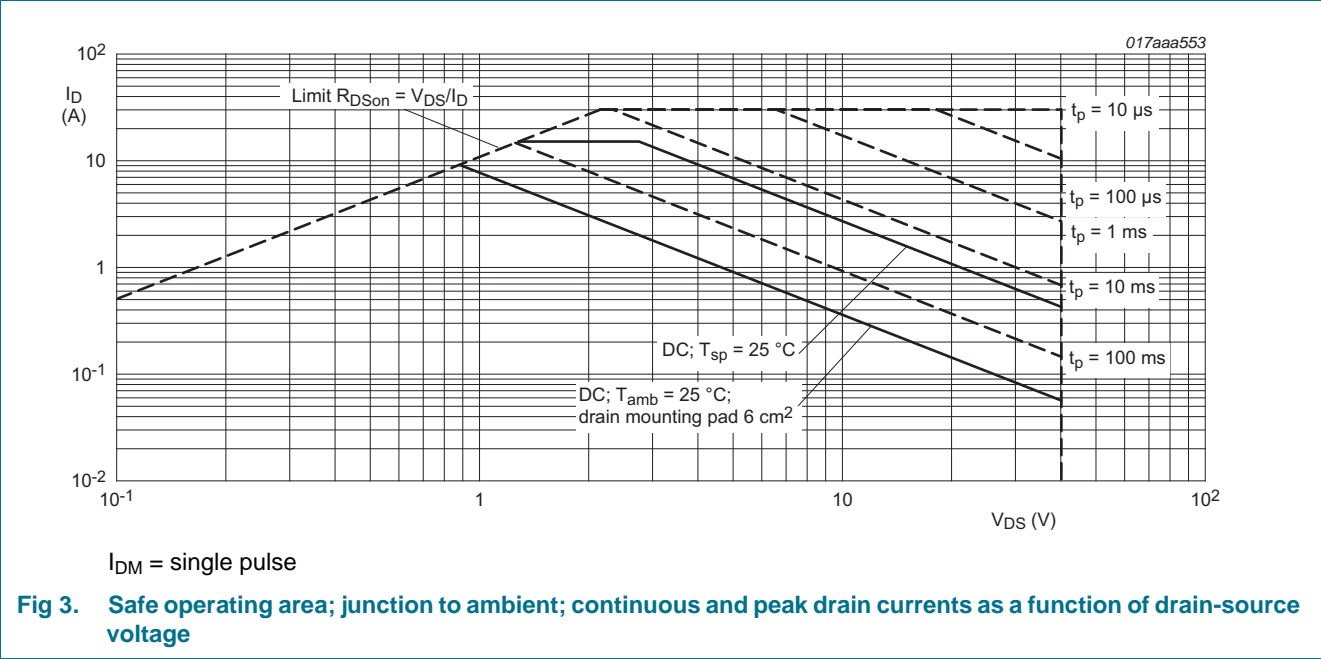
$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100\%$$

**Fig 1. Normalized total power dissipation as a function of junction temperature**



$$I_{der} = \frac{I_D}{I_{D(25^\circ\text{C})}} \times 100\%$$

**Fig 2. Normalized continuous drain current as a function of junction temperature**

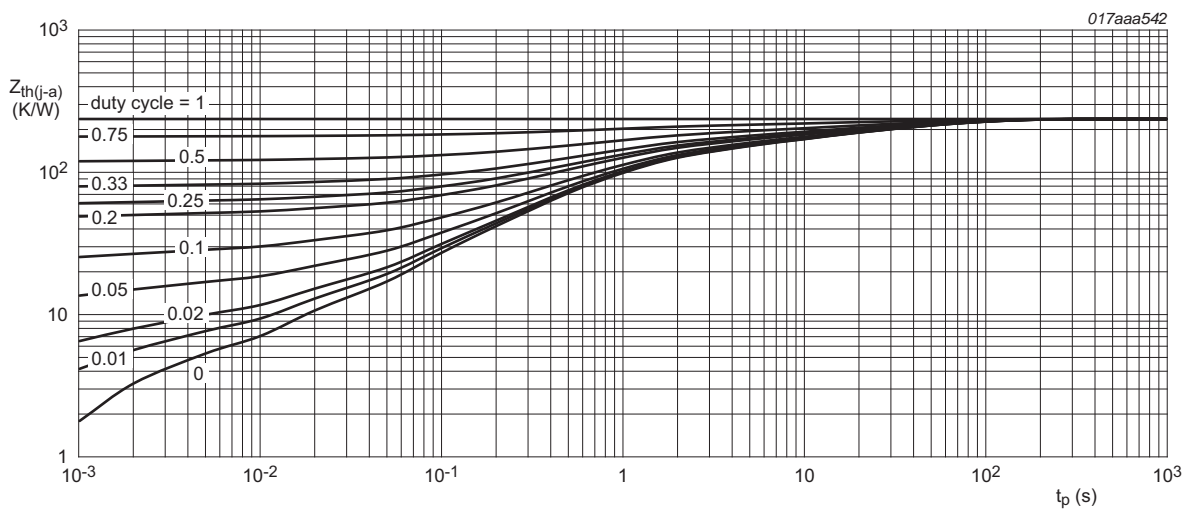


6. Thermal characteristics

Table 6. Thermal characteristics

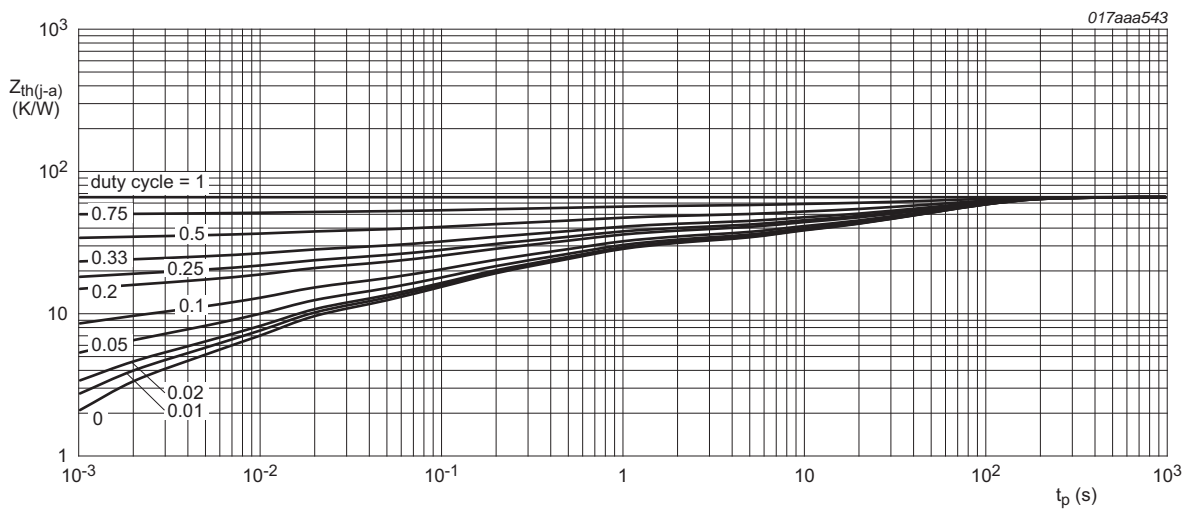
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	235	270 K/W
			[2]	-	67	74 K/W
			[3]	-	33	36 K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	5	10	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain  $6\text{ cm}^2$ .
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain  $6\text{ cm}^2$ ,  $t \leq 5\text{ s}$



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 6 cm<sup>2</sup>

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 7. Characteristics

**Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250\ \mu A$ ; $V_{GS} = 0\ V$ ; $T_j = 25\ ^\circ C$	30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250\ \mu A$ ; $V_{DS} = V_{GS}$ ; $T_j = 25\ ^\circ C$	1	1.5	2	V
$I_{DSS}$	drain leakage current	$V_{DS} = 30\ V$ ; $V_{GS} = 0\ V$ ; $T_j = 25\ ^\circ C$	-	-	1	$\mu A$
		$V_{DS} = 30\ V$ ; $V_{GS} = 0\ V$ ; $T_j = 150\ ^\circ C$	-	-	20	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20\ V$ ; $V_{DS} = 0\ V$ ; $T_j = 25\ ^\circ C$	-	-	100	nA
		$V_{GS} = -20\ V$ ; $V_{DS} = 0\ V$ ; $T_j = 25\ ^\circ C$	-	-	100	nA
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10\ V$ ; $I_D = 9\ A$ ; $T_j = 25\ ^\circ C$	-	12	14.5	m $\Omega$
		$V_{GS} = 10\ V$ ; $I_D = 9\ A$ ; $T_j = 150\ ^\circ C$	-	18	20.5	m $\Omega$
		$V_{GS} = 4.5\ V$ ; $I_D = 3.7\ A$ ; $T_j = 25\ ^\circ C$	-	14	16.5	m $\Omega$
$g_{fs}$	forward transconductance	$V_{DS} = 10\ V$ ; $I_D = 9\ A$ ; $T_j = 25\ ^\circ C$	-	20	-	S
$R_G$	gate resistance	$f = 1\ MHz$	-	1.6	-	$\Omega$
<b>Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$V_{DS} = 15\ V$ ; $I_D = 6\ A$ ; $V_{GS} = 10\ V$ ; $T_j = 25\ ^\circ C$	-	13.7	20.6	nC
$Q_{GS}$	gate-source charge		-	1.73	-	nC
$Q_{GD}$	gate-drain charge		-	1.71	-	nC
$C_{iss}$	input capacitance	$V_{DS} = 10\ V$ ; $f = 1\ MHz$ ; $V_{GS} = 0\ V$ ; $T_j = 25\ ^\circ C$	-	840	-	pF
$C_{oss}$	output capacitance		-	155	-	pF
$C_{rss}$	reverse transfer capacitance		-	65	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 15\ V$ ; $I_D = 5\ A$ ; $V_{GS} = 4.5\ V$ ; $R_{G(ext)} = 6\ \Omega$ ; $T_j = 25\ ^\circ C$	-	9	-	ns
$t_r$	rise time		-	10	-	ns
$t_{d(off)}$	turn-off delay time		-	17	-	ns
$t_f$	fall time		-	9	-	ns
<b>Source-drain diode</b>						
$V_{SD}$	source-drain voltage	$I_S = 2.2\ A$ ; $V_{GS} = 0\ V$ ; $T_j = 25\ ^\circ C$	-	0.8	1.2	V

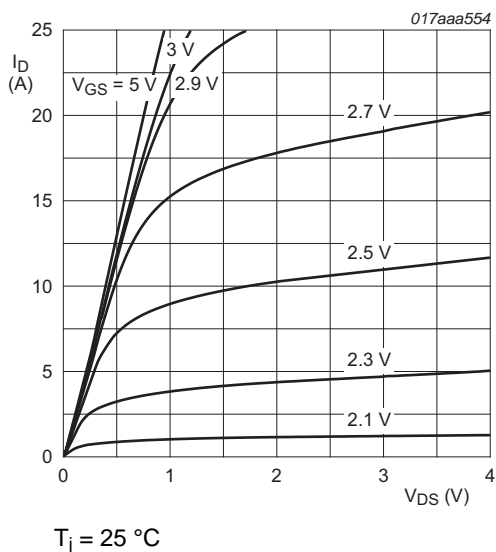


Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values

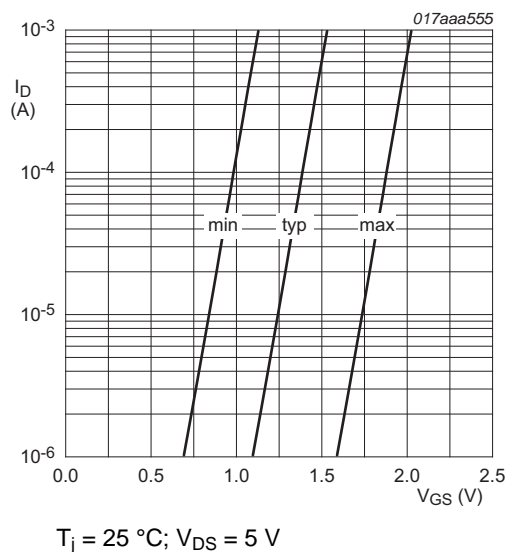


Fig 7. Sub-threshold drain current as a function of gate-source voltage

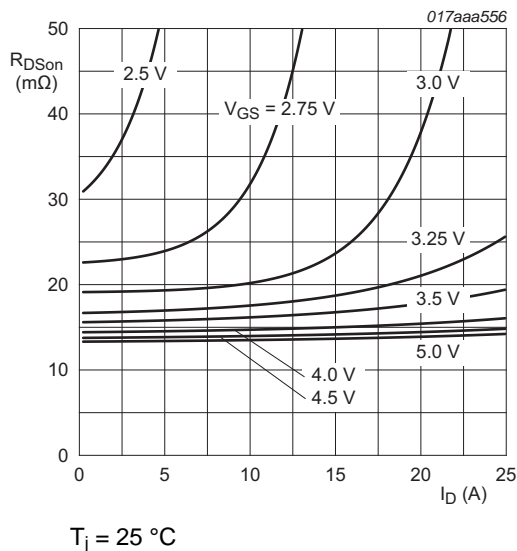


Fig 8. Drain-source on-state resistance as a function of drain current; typical values

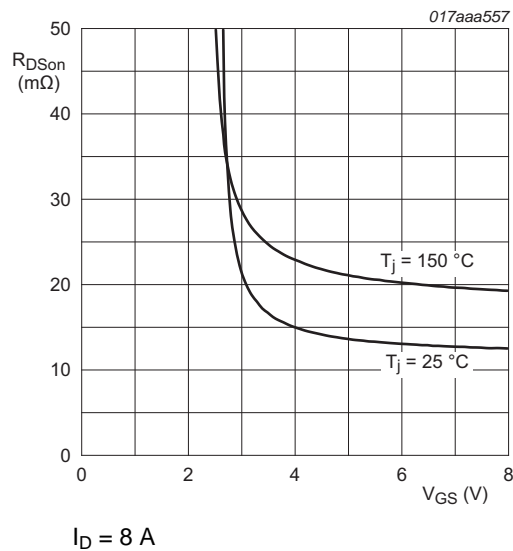


Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

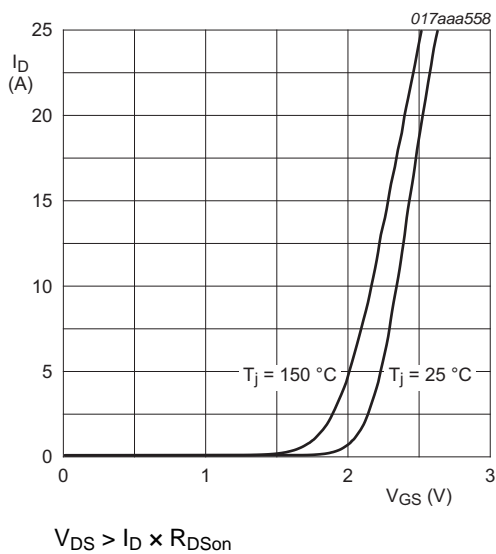


Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

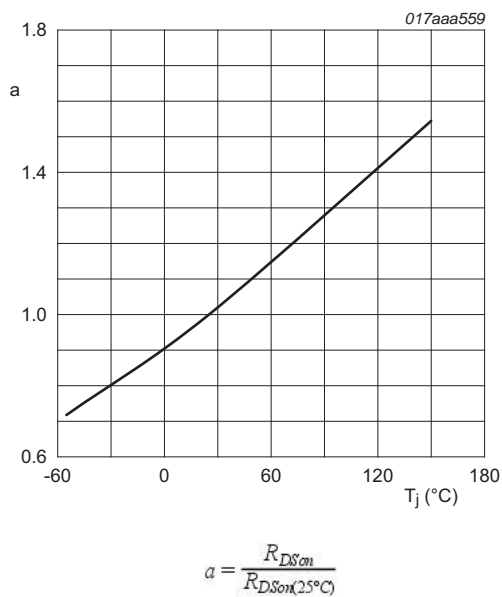


Fig 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

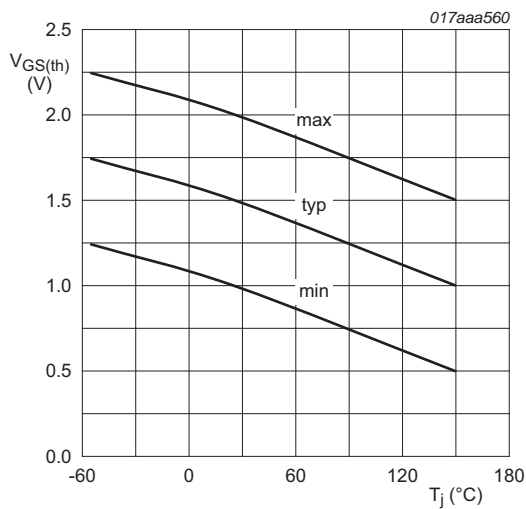


Fig 12. Gate-source threshold voltage as a function of junction temperature

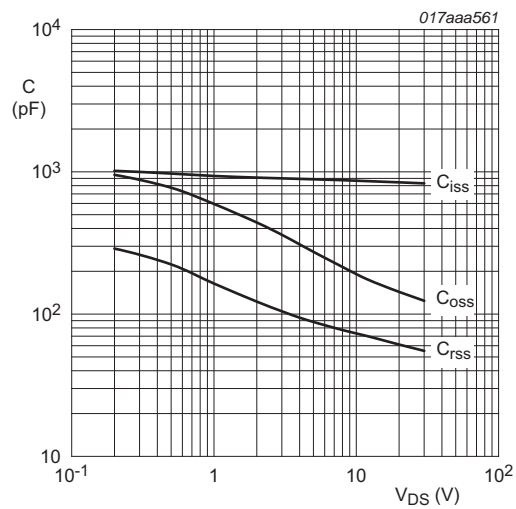
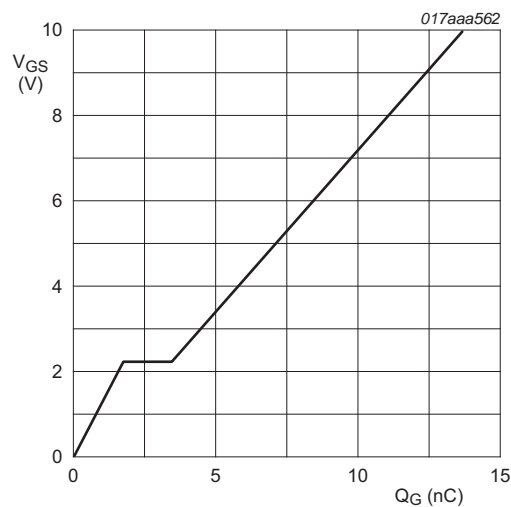


Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values





$I_D = 5\text{ A}$ ;  $V_{DS} = 15\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 14. Gate-source voltage as a function of gate charge; typical values

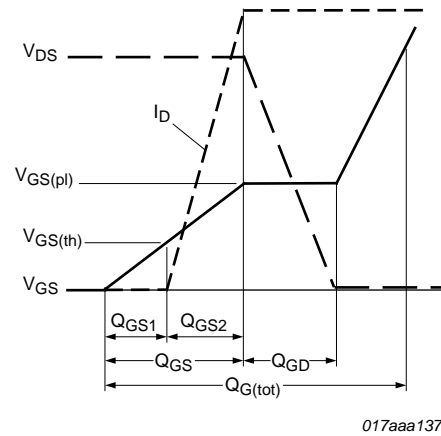
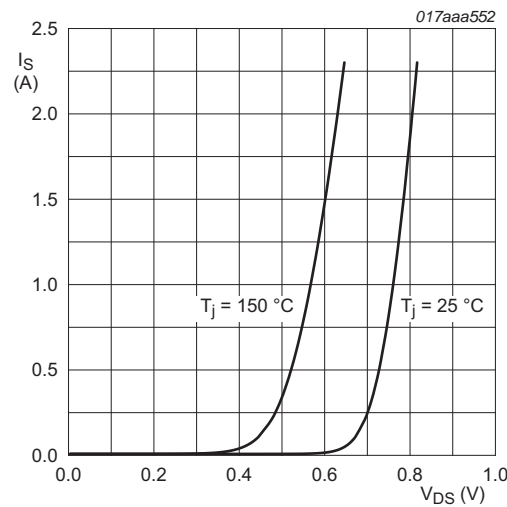


Fig 15. Gate charge waveform definitions

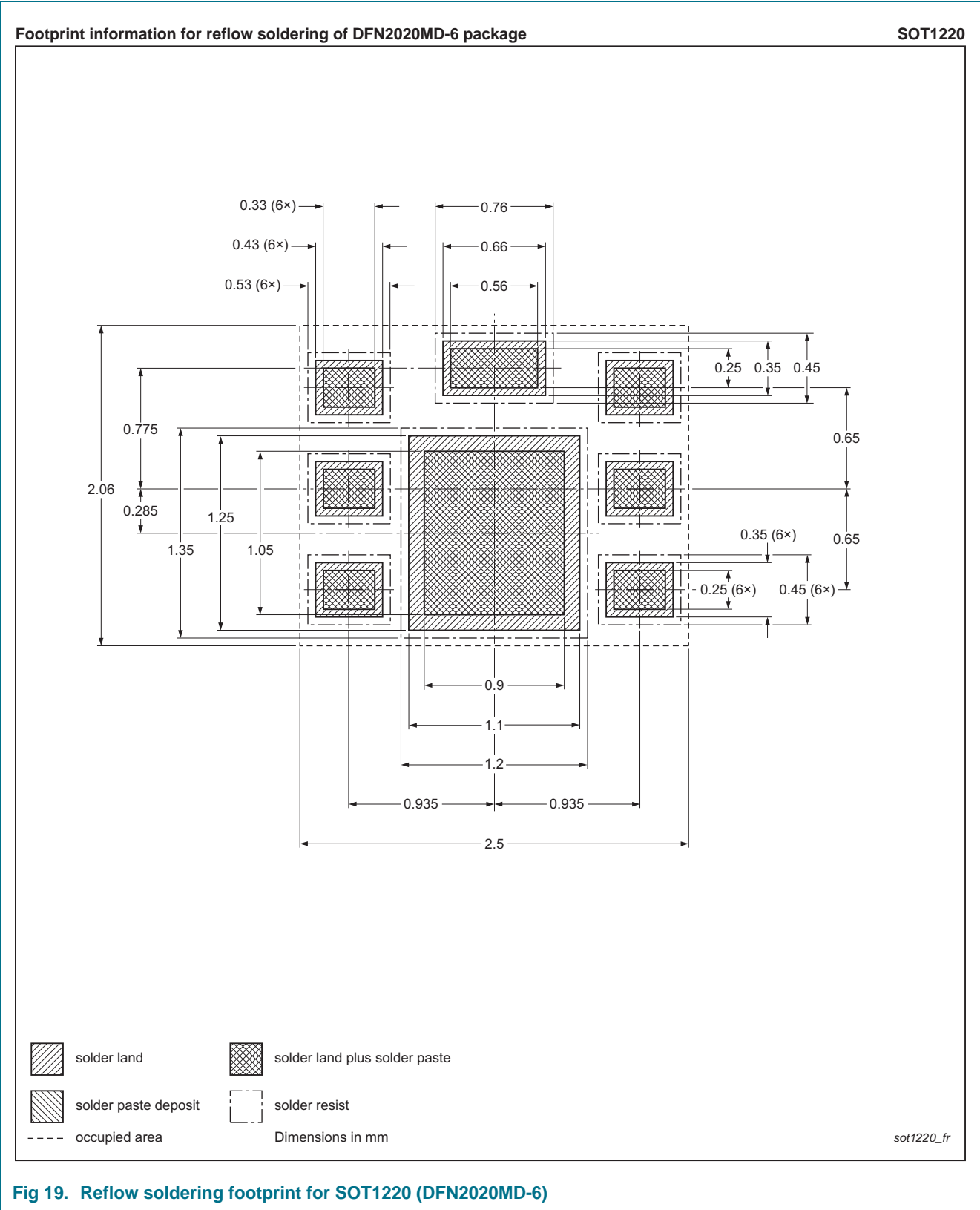


$V_{GS} = 0\text{ V}$

Fig 16. Source current as a function of source-drain voltage; typical values



10. Soldering



## 11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMPB11EN v.1	20120516	Product data sheet	-	-

## 12. Legal information

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Document status <sup>[1] [2]</sup>	Product status <sup>[3]</sup>	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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